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(54) LIQUID CRYSTAL DISPLAY HAVING
ALIGNED PIXEL ELECTRODES AND
FABRICATING METHOD THEREOF

(30) **Foreign Application Priority Data**

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(57) **ABSTRACT**

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Related U.S. Application Data

(62) Division of application No. 09/725,154, filed on Nov. 29, 2000, now Pat. No. 6,778,250.

A liquid crystal display, and a fabricating method thereof, wherein pixel electrodes are highly accurately located relative to opaque elements, such as gate lines, data lines, or auxiliary lines, beneficially by using opaque elements as masking elements when exposing a photosensitive layer through a substrate. The angle of the irradiating light through the substrate can be changed to achieve a desired relative location. A pixel electrode can be located within 1 μm of a data line. Image stain defects can be reduced.

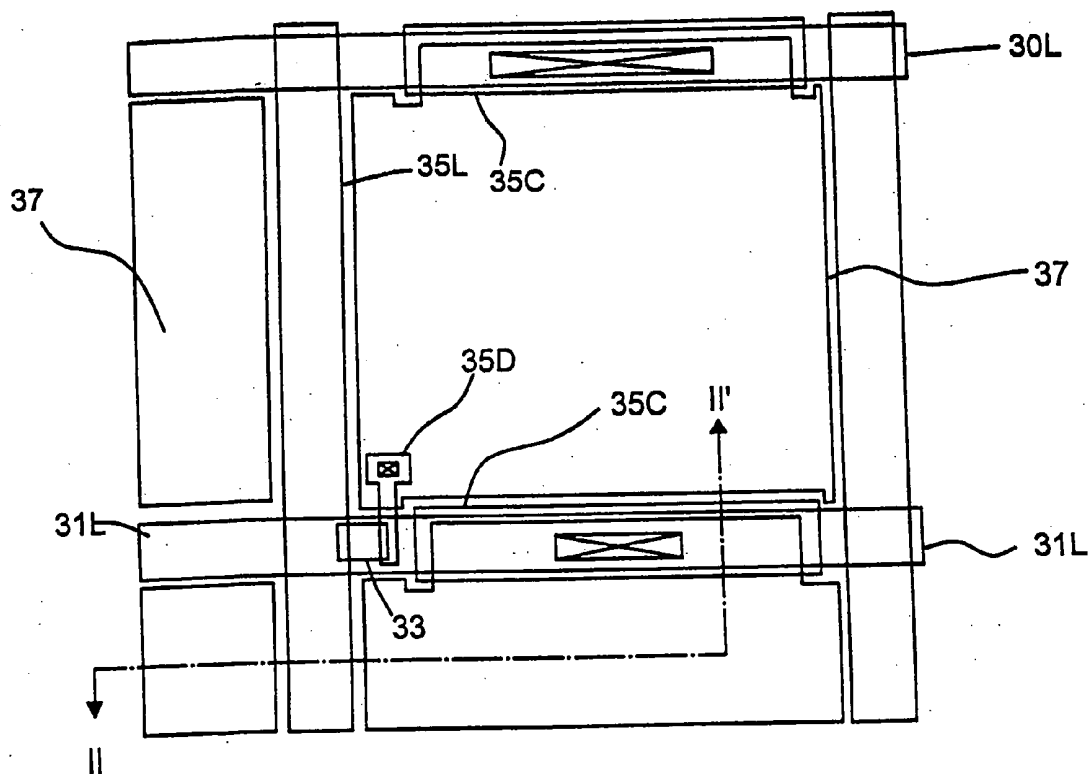


FIG.1
PRIOR ART

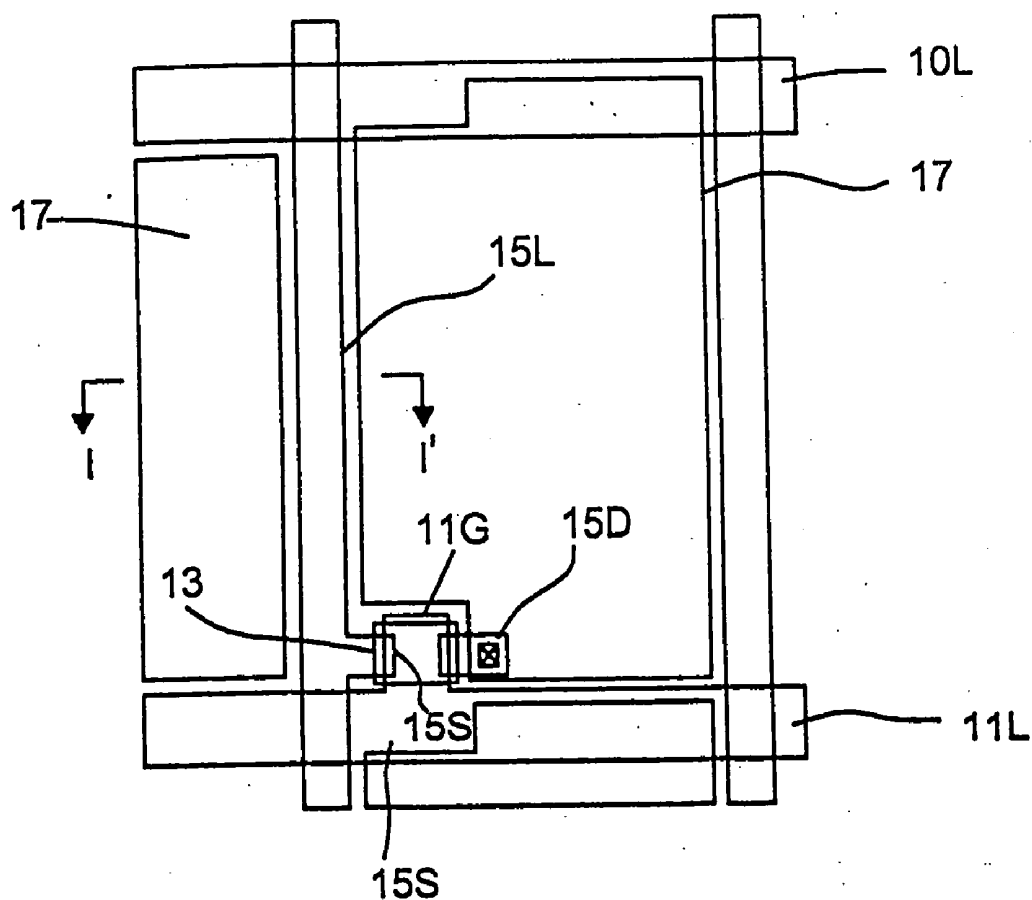


FIG.2
PRIOR ART

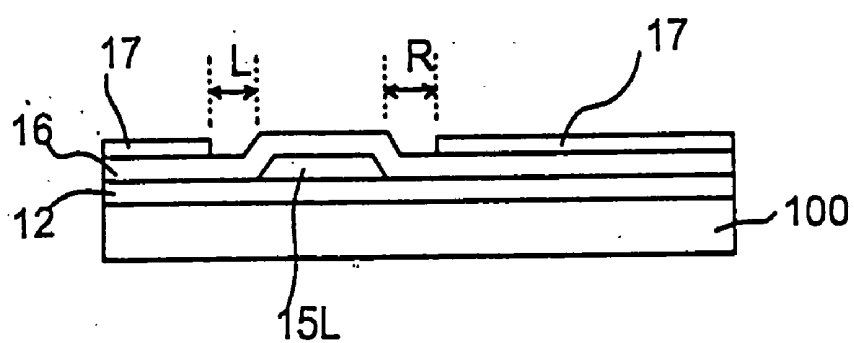


FIG.3

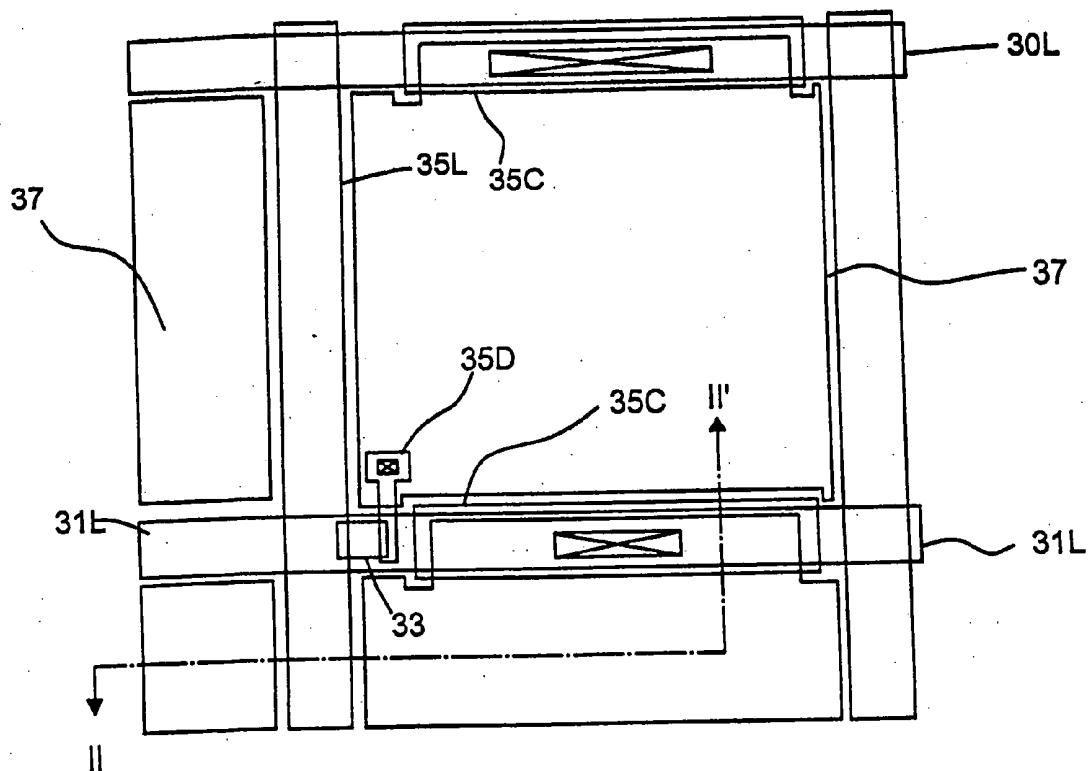


FIG. 5A

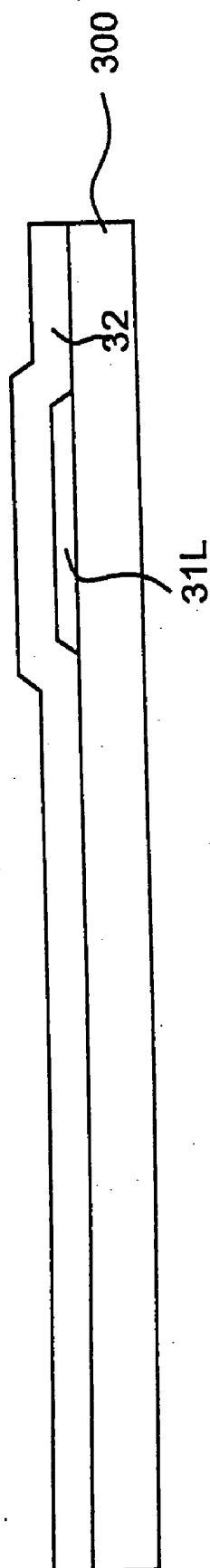


FIG. 5B

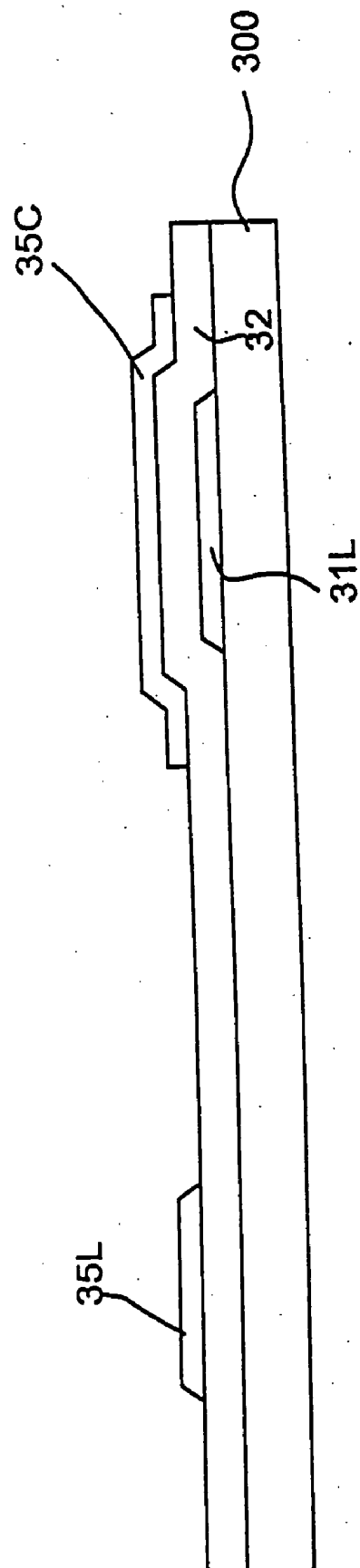


FIG. 5C

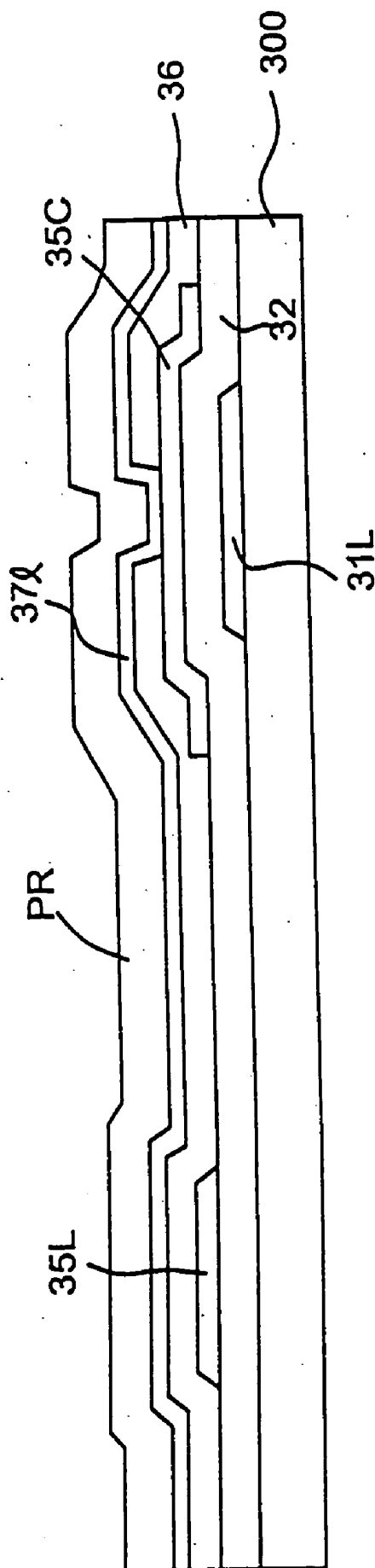


FIG. 5D

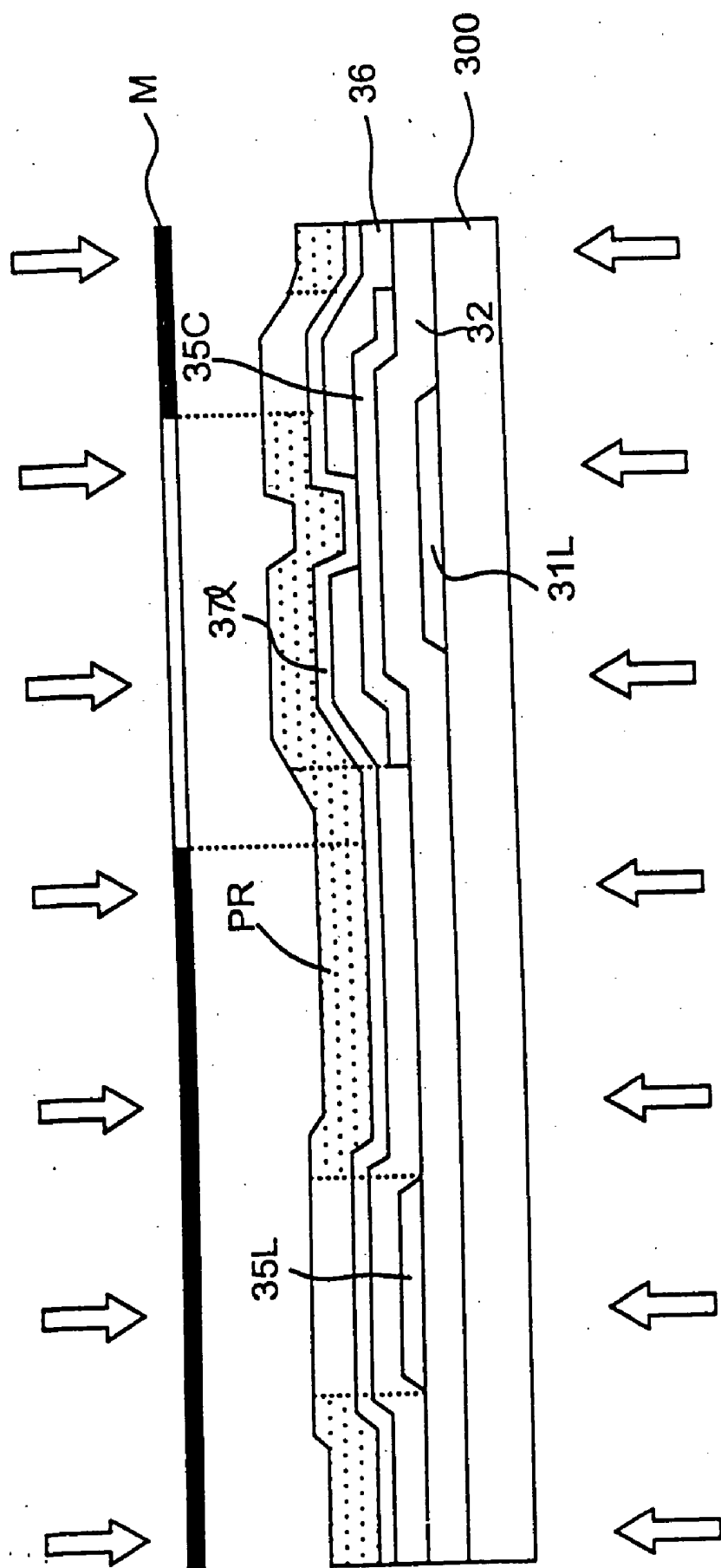


FIG. 6A

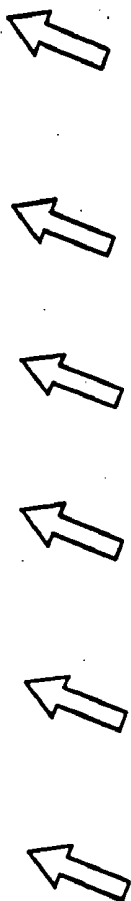
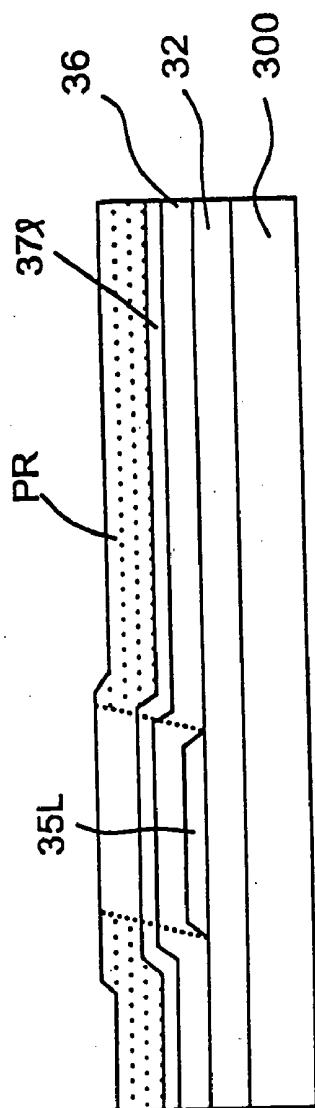


FIG. 6B

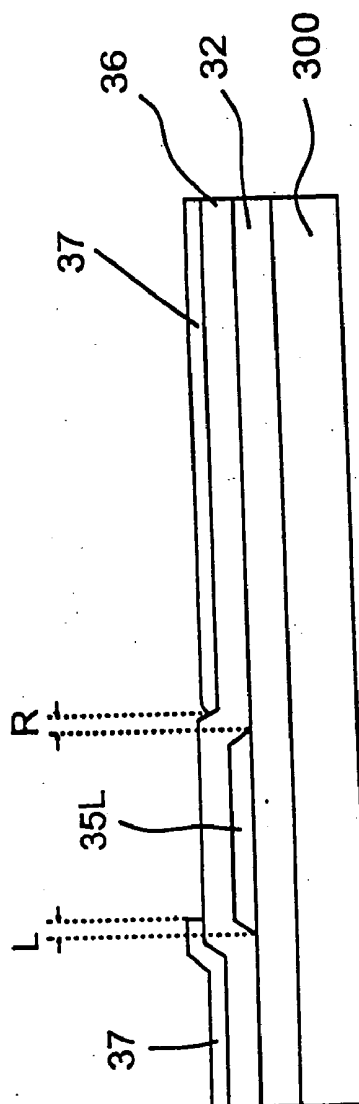
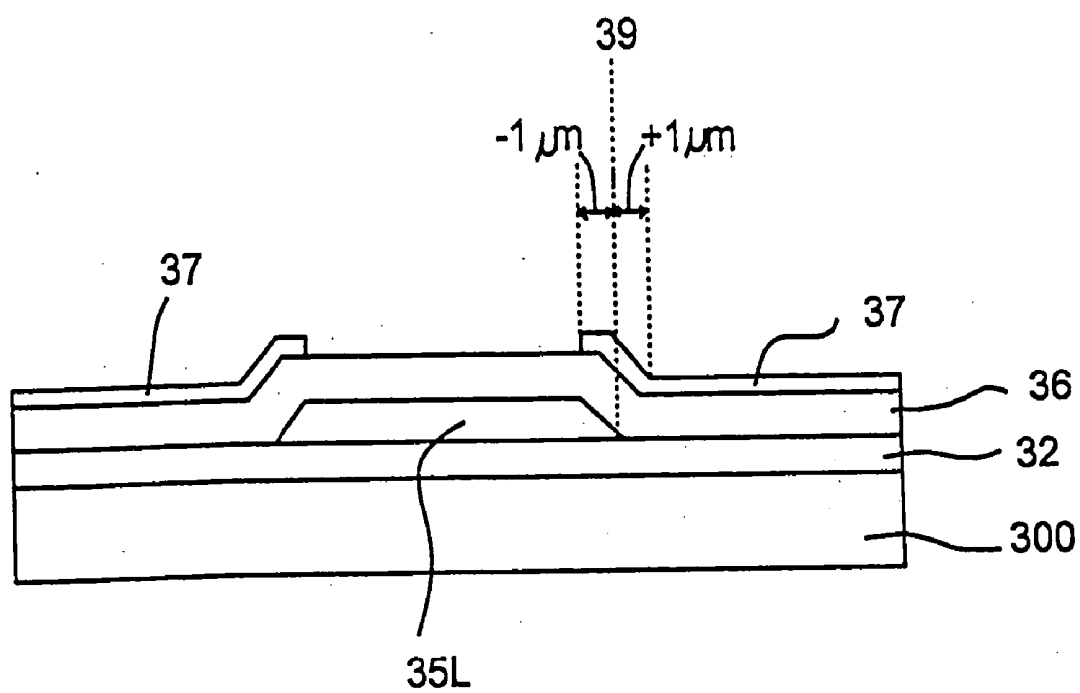


FIG.7



LIQUID CRYSTAL DISPLAY HAVING ALIGNED PIXEL ELECTRODES AND FABRICATING METHOD THEREOF

BACKGROUND OF THE INVENTION

[0001] 1. Field of the Invention

[0002] The present invention relates to liquid crystal displays. More particularly it relates to active matrix liquid crystal displays (AMLCD) having well-aligned pixel electrodes, and to a method of fabricating such active matrix liquid crystal displays.

[0003] 2. Discussion of the Related Art

[0004] An active matrix liquid crystal display is typically fabricated by joining an upper plate to a lower plate, and then injecting a liquid crystal material between the plates. A lower plate usually includes a plurality of pixel cells that are formed from switching devices (usually thin film transistors) and pixel electrodes. Such lower plates further include a plurality of drive lines that connect drive signals to the pixel cells. An upper plate usually includes a plurality of color filters and a common electrode. To complete an active matrix liquid crystal display, polarizing plates are attached to the upper and lower plates.

[0005] FIG. 1 schematically illustrates a typical prior art active matrix liquid crystal display. As illustrated, data lines, including a data line 15L, cross a plurality of gate lines, including gate lines 11L and 10L. The areas between the data lines and the gate lines define pixel cell regions. A thin film transistor (hereinafter abbreviated TFT) that acts as a switching device is formed at intersections between the data lines and the gate lines.

[0006] A TFT includes a gate electrode 11G, which is a protrusion from the gate line 11L, a source electrode 15S, which is a protrusion from the data line 15L, a drain electrode 15D, and an active layer 13. The active layer is overlapped by the electrodes. As shown, a pixel electrode 17 connects to the drain electrode 15D.

[0007] Prior art active matrix liquid crystal displays are usually fabricated using photolithography. For example, to form the data line 15L and source electrode 15S, the gate line 11L and gate electrode 11G, and the drain electrode 15D a metallic layer is deposited on a prepared substrate. The deposited metallic layer is then coated with a photoresist layer. The deposited metallic layer is then patterned by selectively exposing the photoresist layer through a prepared mask using a light source that is above the metallic layer. The exposed photoresist layer is then etched to leave metallic conductors for the lines and electrodes. Pixel electrodes are then formed in the same manner. However, pixel electrodes are typically fabricated after the lines and electrodes. Significantly, the pixel electrodes are fabricated from a transparent material.

[0008] While the photolithographic process described above has proven useful, it has problems. One particular problem when fabricating prior art active matrix liquid crystal displays is the likelihood of misalignment of the pixel electrodes relative to other features. Such misalignment may be caused by misalignment of exposure masks or of the exposure apparatus, or by an etch deviation due to etch conditions.

[0009] FIG. 2 assists the understanding of pixel electrode misalignment by showing a cross-sectional view taken along the line I-I' of FIG. 1. Initially, a gate insulating layer 12 is formed on a substrate 100. The data line 15L is then photolithographically formed on the gate insulating layer 12. A protection layer 16 is then formed over the structure. Pixel electrodes 17 are then photolithographically formed on the protection layer 16. Ideally, the data line 15L is centered between the pixel electrodes such that the intervals L and R are the same. Unfortunately, the locations of the pixel electrodes can deviate from their intended locations. Such deviations can be caused divisional exposure.

[0010] With divisional exposure, each exposure step requires new exposure equipment, such as a photomask, to be set-up. Thus, it is very difficult to control the intervals L and R such that they are even. As a result, image defects referred to as image stains are created. Furthermore, cross-talk between the pixel electrodes and the data lines becomes more severe due to deviations of parasitic capacitances.

[0011] Therefore, an improved active matrix liquid crystal display, and a new method of fabricating such an active matrix liquid crystal display, having accurately positioned pixel electrodes would be beneficial.

SUMMARY OF THE INVENTION

[0012] Accordingly, the principles of the present invention are directed to a liquid crystal display and to a fabricating method thereof that substantially obviate one or more of the problems due to limitations and disadvantages of the related art.

[0013] An object of the present invention is to provide a liquid crystal display, and a fabricating method thereof, which has accurately positioned pixel electrodes. Uniform intervals between pixel electrodes and data lines are created by patterning the pixel electrodes using a self-alignment technique by exposing the pixel electrodes through a substrate.

[0014] Additional features and advantages of the invention will be set forth in the description which follows and in part will be apparent from the description, or may be learned by practice of the invention. The objectives and other advantages of the invention will be realized and attained by the structure particularly pointed out in the written description and claims hereof as well as the appended drawings.

[0015] To achieve these and other advantages and in accordance with the purpose of the present invention, as embodied and broadly described, the present invention includes a liquid crystal display, wherein a plurality of gate lines cross a plurality of data lines to define locations of a plurality of pixel cells. Switching devices are formed at intersections of gate lines and data lines. Pixel electrodes are formed at the pixel cells, and each pixel electrode connects to a switching device. The pixel electrodes are beneficially formed such that the distance between each side of a pixel electrode and a side of a data line adjacent to the pixel electrode is accurately controlled, preferably less than or equal to 1 μm .

[0016] In another aspect, the present invention includes the steps of providing a substrate, fabricating a plurality of gate lines and a plurality of crossing data lines that define a plurality of pixel cells, and forming switching devices at

intersections of the gate lines and the data lines. The present invention further includes the steps of depositing a protection layer over the switching devices, gate lines, data lines, and substrate, forming contact holes through the protection layer to expose electrodes of the switching devices, and forming a transparent conductive layer over the exposed surface of the substrate, including the exposed electrodes. Additional steps include forming a negative type photoresist layer on the transparent conductive layer, selectively exposing the negative type photoresist layer through the substrate such that the data lines act as masks, forming a photoresist pattern by developing the selectively-exposed photoresist layer, and etching the transparent conductive layer. Beneficially, before developing the negative type photoresist layer an exposing source and a mask that are above the photoresist layer can also be used to expose the transparent conductive layer.

[0017] It is to be understood that both the foregoing general description and the following detailed description are exemplary and explanatory and are intended to provide further explanation of the invention as claimed.

BRIEF DESCRIPTION OF THE DRAWING

[0018] The accompanying drawings, which are included to provide a further understanding of the invention and are incorporated in and constitute a part of this specification, illustrate embodiments of the invention and together with the description serve to explain the principles of the invention.

[0019] In the drawings:

[0020] FIG. 1 shows a simplified schematic view of a prior art LCD;

[0021] FIG. 2 is a cross-sectional view along the line I-I' in FIG. 1;

[0022] FIG. 3 shows a simplified schematic view of an LCD according to an embodiment of the present invention;

[0023] FIG. 4 is a cross-sectional view along the line II-II' in FIG. 3;

[0024] FIGS. 5A to 5G show cross-sectional views of the LCD shown in FIG. 3 during its fabrication;

[0025] FIGS. 6A and 6B are cross-sectional views showing how an interval between a pixel electrode and a data line can be controlled by using the direction of an exposing light; and

[0026] FIG. 7 is a cross-sectional view of an LCD that presents the interval range between a pixel electrode and a data line according to the present invention.

DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS

[0027] Reference will now be made in detail to the preferred embodiment of the present invention, example of which is illustrated in the accompanying drawings.

[0028] FIG. 3 shows a simplified schematic view of an LCD according to an embodiment of the present invention, while FIG. 4 shows a cross-sectional view of that embodiment taken along the line II-II' of FIG. 3. The illustrated embodiment has a structure in which a plurality of gate lines

cross with a plurality of data lines so as to define locations for a plurality of pixel cells. FIG. 3 shows a data line 35L crossing a gate line 31L and a TFT switching device formed at the intersection. The TFT is constructed such that it overlaps with the gate line 31L, the data line 35L, and with a drain electrode 35D. The TFT includes an active layer 33 that is overlapped with the gate line 31L. This reduces leakage current due to exposure by back lighting. A pixel electrode 37 is then photolithographically formed in the pixel area between gate lines and data lines. The pixel electrode electrically connects to the drain electrode 35D. Furthermore, the pixel electrode overlaps an adjacent gate line 30L, producing a storage capacitor.

[0029] According to the principles of the present invention the pixel electrode 37 is formed using self-alignment by exposing a transparent conductor layer that was deposited on the LCD structure by passing light through the LCD structure such that the data line, an auxiliary electrode, or the gate line acts as a mask. By using the data lines and/or the gate lines as masking lines the intervals between the resulting pixel electrodes and the masking lines becomes uniform.

[0030] FIG. 4 illustrates the intervals. As shown, an interval designated "L" on the left of a data line 35L is equal to an interval "R" on the right. Therefore, the image stain defect that arises from uneven intervals between pixel electrodes and data lines is prevented.

[0031] Still referring to FIG. 4, auxiliary electrodes 35C comprised of the same substance as the data lines are included in the LCD. Each auxiliary electrode, which electrically contacts a pixel electrode, increases the capacitance between a gate line 31L and the contacted pixel electrode 37. This increase in capacitance is partially a result of a reduction in the thickness of a dielectric layer between the gate line 31L and the pixel electrode 37.

[0032] FIG. 5A to FIG. 5G show cross-sectional views of the LCD illustrated in FIGS. 3 and 4 during its fabrication. The cross-sectional views are taken along the II-II' in FIG. 3.

[0033] Referring to FIG. 5A, a first conductive layer is deposited on a transparent substrate 300. The first conductive layer is photolithographically patterned to form the gate line 31L. A transparent gate insulating layer 32 is then deposited on the gate line 31L and the substrate 300. An active layer, which is not shown in FIGS. 5A through 5G, is then formed at a predetermined location on the gate insulating layer 32.

[0034] Referring now to FIG. 5B, a second conductive layer is then deposited over the gate insulating layer 32. An auxiliary electrode 35C and a data line 35L are then formed using photolithography. Additionally, a drain electrode that is not shown in the drawing is also formed on the gate insulating layer 32 at this time.

[0035] Referring now to FIG. 5C, a protection layer 36 is then applied to the exposed substrate. A contact hole that exposes a portion of the auxiliary electrode 35C is then photolithography formed through the protection layer. While not shown in the figures another contact hole that exposes a portion of the drain electrode is also formed. A transparent conductive layer 37I is then deposited over the exposed surface or the substrate. Then, the transparent conductive layer 37I is coated with a negative type photoresist layer PR.

[0036] Referring to FIG. 5D, exposure of the negative type photoresist layer PR is performed to define photoresist patterns for the pixel electrodes. As shown in FIG. 5D, the photoresist layer PR is exposed from both sides. This is performed by passing light through the transparent substrate, where the opaque data line 35L and the opaque gate line 31L act as masks, and from above, where a mask M is used. However, if the pixel electrodes are not being used to form storage capacitors with the gates, the front side exposure can be skipped. The mask M block light everywhere but near the gate layer 31L/auxiliary electrode 35C. As shown in FIG. 5D, a small area of the negative type photoresist layer PR is blocked both by the mask M and by the auxiliary electrode 35C.

[0037] By exposing the negative type photoresist layer PR through the substrate (referred to as back side exposure) the exposing light exposes the negative type photoresist layer PR everywhere except where the gate line 31L, the data line 35L, and the auxiliary electrode 35C (if used) mask the photoresist layer PR. Furthermore, it should be understood that the exposure steps need not be performed simultaneously. For example, exposure can be carried out by first exposing from the front side and then from the back, or vice versa.

[0038] Referring now to FIG. 5E, the exposed photoresist layer PR is then developed to form a photoresist pattern PR. Referring now to FIG. 5F, pixel electrodes 37 are then formed by etching the transparent conductive layer while using the photoresist pattern PR as a mask. As shown, each pixel electrode 37 is aligned with a data line 35L since that data line acted as a mask during exposure of the negative type photoresist layer PR. Thus, a uniform interval between the pixel electrode 37 and the data line 35L is provided and image stains defects are prevented.

[0039] The principles of the present invention address the problem of irregular intervals between data lines and pixel electrodes that result from misalignment of exposure equipment. This is achieved by using the data lines, gate lines, or auxiliary lines as a mask by exposing a photoresist through the substrate, back side exposure.

[0040] However, the principles of the present invention accomplish even more. For example, they enable the control of the intervals between pixel electrodes and data lines, gate lines, or auxiliary lines. Such control is explained with the assistance of FIGS. 6A and 6B. For the convenience those figures use the same nomenclature as FIGS. 5A through 5B. Referring now to FIG. 6A, back side exposure of the negative type photoresist pattern PR is carried out through the substrate 300 and through the transparent conductive layer 37I. However, during back-side exposure the angle of irradiation through the substrate is controlled such that the location of the resulting pixel electrode relative to the data line 35L is controlled. FIG. 6B shows the end result of irradiating the data line 35L with light as shown in FIG. 6A. The pixel electrode on the left side of the data line 35L overlaps with that data line, while the pixel electrode on its right side is separated from the data line 35L by an interval "R". One benefit of the structure that results from FIG. 6B is that light leakage from the left of the data lines is prevented. Of course, light leakage from the right of the data lines can be prevented by changing the angle of the exposing light. Therefore, the intervals between pixel electrodes 37

and data lines 35L can be controlled by controlling the direction and angle of light irradiation through the substrate.

[0041] The principles of the present invention can accomplish even more. In high quality LCD it is very important to control critical dimensions, such as the intervals between pixel electrodes 37 and data lines 35L, by changing the irradiation angle. For example, the FIG. 7 illustrates a desirable result of controlling the interval 39 within $\pm 1 \mu\text{m}$ from the pixel electrode 37, using an edge of the data line 35L as a reference. The critical dimension is thereby controlled by photolithography.

[0042] Accordingly, the principles of the present invention enables a reduce in the image stain defect by patterning pixel electrodes such that the pixel electrodes self-align with another element by back-side exposing a photosensitive layer through a substrate. If a data line is the element that is used to self-align the pixel electrodes, a uniform interval between the pixel electrodes and the data lines can result. Moreover, the principles of the present invention enables control of an interval between pixel electrodes and data lines by changing the irradiating angle through the substrate.

[0043] It will be apparent to those skilled in the art that various modifications and variation can be made in the present invention without departing from the spirit or scope of the invention. Thus, it is intended that the present invention covers the modifications and variations of this invention provided they come within the scope of the appended claims and their equivalents.

What is claimed is:

1. A liquid crystal display, comprising:

a plurality of gate lines;

a plurality of data lines that cross said plurality of gate lines so as to define a plurality of pixel cells;

a plurality of switching devices at intersections between said plurality of gate lines and said plurality of data lines; and

a plurality of pixel electrodes, wherein each pixel electrode is in a pixel cell, and wherein each pixel electrode electrically connects to a switching device;

wherein a distance between an edge of each pixel electrode is within about $1 \mu\text{m}$ of an edge of a data line.

2. The liquid crystal display according to claim 1, wherein two edges of each data line are within about $1 \mu\text{m}$ of adjacent pixel electrodes.

3. The liquid crystal display according to claim 1, further including a protection layer disposed between said plurality of pixel electrodes and said plurality of data lines.

4. The liquid crystal display according to claim 1, wherein each pixel electrode overlaps a data line.

5. The liquid crystal display according to claim 4, wherein each pixel electrode is separated from an adjacent data line.

6. The liquid crystal display according to claim 1, further including an auxiliary electrode that overlaps a first gate line, wherein said auxiliary electrode is disposed between said overlapped first gate line and a first pixel electrode, and wherein said auxiliary electrode electrically connects to said first pixel electrode.

7. A method of fabricating a liquid crystal display, comprising the steps of:

forming a plurality of gate lines adjacent a front side of a substrate;

forming a plurality of data lines over said plurality of gate lines, wherein said gate lines cross said data lines to define a plurality of pixel cells;

forming a switching device for each pixel cell at an intersection of a gate line and a data line, wherein each switching device includes an electrode;

depositing a protection layer over said switching devices, over said data lines, and over said pixel cells;

photolithographically forming contact holes through said protection layer to expose portions of said switching device electrodes;

forming a transparent conductive layer over said protection layer and over said exposed portions of said switching devices;

forming a negative type photoresist layer on said transparent conductive layer;

exposing said negative type photoresist layer by passing light through a back-side of said substrate;

forming a photoresist pattern by developing said exposed negative type photoresist layer; and

etching said transparent conductive layer using said photoresist pattern as an etch mask.

8. The method of fabricating a liquid crystal display according to claim 7, further comprising the step of exposing said negative type photoresist layer using light passed through a light mask over said front side.

9. The method of fabricating a liquid crystal display according to claim 8, wherein the step of exposing said negative type photoresist layer using light passed through a light mask is not performed simultaneously with said back-side exposure.

10. A method of fabricating a liquid crystal display, comprising the steps of:

forming an opaque element on an area over a front-side of a transparent substrate, wherein said substrate has a back-side opposite said front-side;

depositing a transparent layer over said opaque element and over said area;

forming a negative type photoresist layer on said transparent layer;

exposing said negative type photoresist layer by passing light through said back-side, wherein said opaque element masks said negative type photoresist layer;

developing said exposed negative type photoresist layer to form a resist pattern; and

etching said transparent layer using said resist pattern as a resist mask.

11. A method according to claim 10, wherein said step of forming an opaque element includes forming conductive lines.

12. A method according to claim 10, wherein said step of depositing a transparent layer includes forming a transparent conductive layer.

13. A method according to claim 12, wherein said step of forming an opaque element includes forming conductive lines.

14. A method according to claim 10, wherein said step of exposing said negative type photoresist layer is performed by passing light at an angle through said back-side.

15. A method of fabricating a liquid crystal display, comprising the steps of:

forming a gate electrode on a front-side of a transparent substrate, wherein said substrate has a back-side opposite said front-side;

forming a gate insulating layer over said gate electrode and over said front-side;

forming a data electrode over said gate insulating layer;

forming a protection layer over said gate insulating layer and over said data electrode;

forming a conductive transparent layer over said protection layer;

forming a negative type photoresist layer over said transparent layer;

exposing said negative type photoresist layer by passing light through said back-side such that said data electrode acts as a light mask;

developing said exposed negative type photoresist layer to form a resist pattern; and

etching said transparent layer using said resist pattern as a resist mask.

16. A method of fabricating a liquid crystal display according to claim 15, wherein said step of forming a data electrode forms an auxiliary electrode over said gate electrode.

17. A method of fabricating a liquid crystal display according to claim 16, wherein said auxiliary electrode acts as a second light mask during said step of exposing said negative type photoresist layer.

18. A method of fabricating a liquid crystal display according to claim 16, further including a step of forming a hole through said protection layer.

19. A method of fabricating a liquid crystal display according to claim 18, wherein said step of forming a transparent layer includes a step of electrically connecting said transparent layer to said auxiliary electrode.

20. A method of fabricating a liquid crystal display according to claim 15, wherein said step of exposing said negative type photoresist layer includes passing light at an angle through said back-side.

* * * * *

专利名称(译)	具有对准的像素电极的液晶显示器及其制造方法		
公开(公告)号	US20040239824A1	公开(公告)日	2004-12-02
申请号	US10/885781	申请日	2004-07-08
[标]申请(专利权)人(译)	AHN BYUNG CHUL 李炫KYU		
申请(专利权)人(译)	AHN BYUNG哲 李铉圭		
当前申请(专利权)人(译)	LG DISPLAY CO. , LTD.		
[标]发明人	AHN BYUNG CHUL LEE HYUN KYU		
发明人	AHN, BYUNG-CHUL LEE, HYUN-KYU		
IPC分类号	G02F1/133 G02F1/1343 G02F1/1362 G02F1/1335		
CPC分类号	G02F1/134336 G02F1/13439 G02F1/1362 G02F1/136286		
优先权	1019990018903 1999-05-25 KR		
其他公开文献	US6919932		
外部链接	Espacenet USPTO		

摘要(译)

一种液晶显示器及其制造方法，其中像素电极相对于不透明元件（例如栅极线，数据线或辅助线）高度精确地定位，有利地通过在通过光敏层曝光光敏层时使用不透明元件作为掩模元件。基质。可以改变通过基板的照射光的角度以实现期望的相对位置。像素电极可位于数据线的1毫米内。可以减少图像污点缺陷。

